20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A.	Silicon Transistors			TELEPHONE: (973) 376-2922 (212) 227-6005 FAX: (973) 376-8960	
I					
-	2N3395,6,7,	8			
electrical characteristi	cs: (25°C) (unit	ess otherwise specifi	ed)		
DC Characteristics		Sym.	Min	Max.	Units
Collector cutoff current ($V_{CB} = 25V$, $I_{+} = 0$) Emitter cutoff current ($V_{EB} = 5V$, $I_{C} = 0$) Forward current transfer ratio ($V_{CE} = 4.5V$,		Т _{сво} Г _{ево} Б		0.1 0.1	ua ua
$I_{\rm C}=2$ ma)	2N3395 2N3396 2N3397 2N3398	հ _{թե}	150 90 55 55	500 500 500 800	
Grounded-base, open circuit output ($V_{CE} = 10V$) Collector Capacitance ($I_E = 0$, f=1 mc)		C us	4.5	10	þſ
absolute maxi Voltages	mum ratings:	(25°C) (unit	ess oth <mark>erwise speel</mark>	fied)	
Collector to Emitter Emitter to Base Collector-to Base		V _{CEO} V _{EBO} V _{CBO}	25 5 25	V V	
Current					
Collector (Steady State)*		I _C	100	กาล	
Dissipation					
Total Power (Free air at 25°C)** Total Power (Free air at 55°C)**		P P	360 250	ทพ กาพ	
lemperature					
Storage Operating Lead Temperature, 1/16'' ± 1/32'' from case for 10 seconds max.		T _{NIG} T _J T _L	-55°C to +150°C +125°C +260°C		



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